## **EAST Search History**

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	. 2227	(SOI near3 thickness)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/10 16:19
L2	13	(SOI near3 thickness near3 nanometer)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2006/06/10 16:22
L3	541	(HVMOS or (high adj voltage)) with SOI	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/10 16:23
L4	40	(HVMOS or (high adj voltage)) with SOI with (thick or thickness)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/10 16:31
L5	1051	257/347.ccls. and "2000"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/06/10 16:32
L6	28	257/347.ccls. and (("2000" adj (nm or nanometer)) or "2000nm")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2006/06/10 16:32
L7	170	257/347,350,353.ccls. and @pd>"20060119"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/06/10 17:00
L9	51	257/391,392,500,501.ccls. and @pd>"20060119"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/06/10 17:00